



A Product Line of Diodes Incorporated



50V NPN LOW SATURATION TRANSISTOR IN SOT23

Features

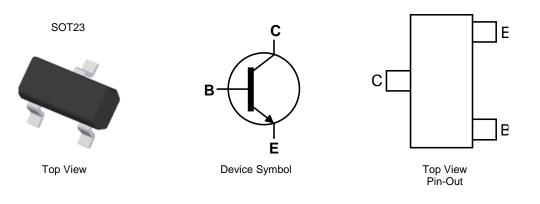
- BV_{CEO} > 50V
- I_C = 1.25A Continuous Collector Current
- 500mW Power Dissipation
- Low Saturation Voltage V_{CE(sat)} < 330mV @ 1.25A
- R_{CE(SAT)} = 160mΩ for a Low Equivalent on-Resistance
- Complementary PNP type: FMMTL720
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.008 grams (Approximate)

Applications

- MOSFET Gate Driving
- DC-DC / DC-AC Converters
- Regulator
- LED Driver
- Motor Control



Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMTL619TA	AEC-Q101	L69	7	8	3,000
Notes: 1 No purposely added lead Fully FLI Directive 2002/05/FC (PoHS) & 2011/65/FLI (PoHS 2) compliant					

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http:// www.diodes.com/products/packages.html.

Marking Information



L69 = Product Type Marking Code





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	100	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	lc	1.25	A
Peak Pulse Current	I _{CM}	2	A
Base Current	IB	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	500	mW
Power Dissipation (Note 6)	PD	675	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ extsf{ heta}JA}$	250	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	185	°C/W
Thermal Resistance, Junction to Lead (Note 7)	R _θ JL	197	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

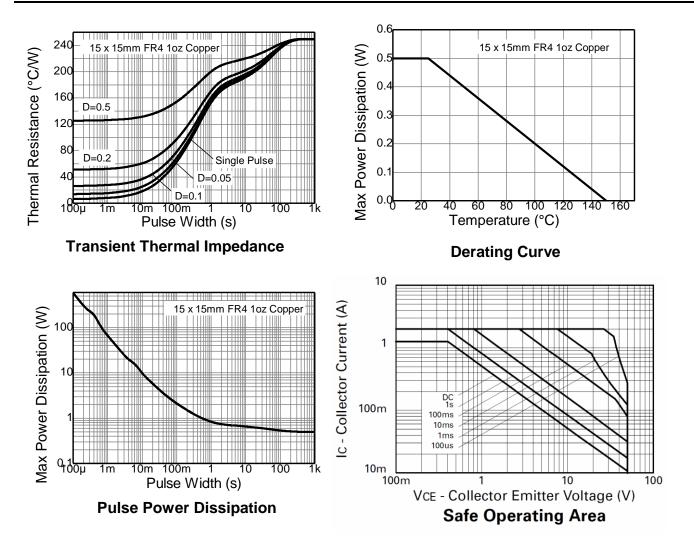
Notes: 5. For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 5, except the device is measured at t ≤ 5 seconds.
7. Thermal resistance from junction to solder-point (at the end of the collector lead).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





Thermal Characteristics and Derating information





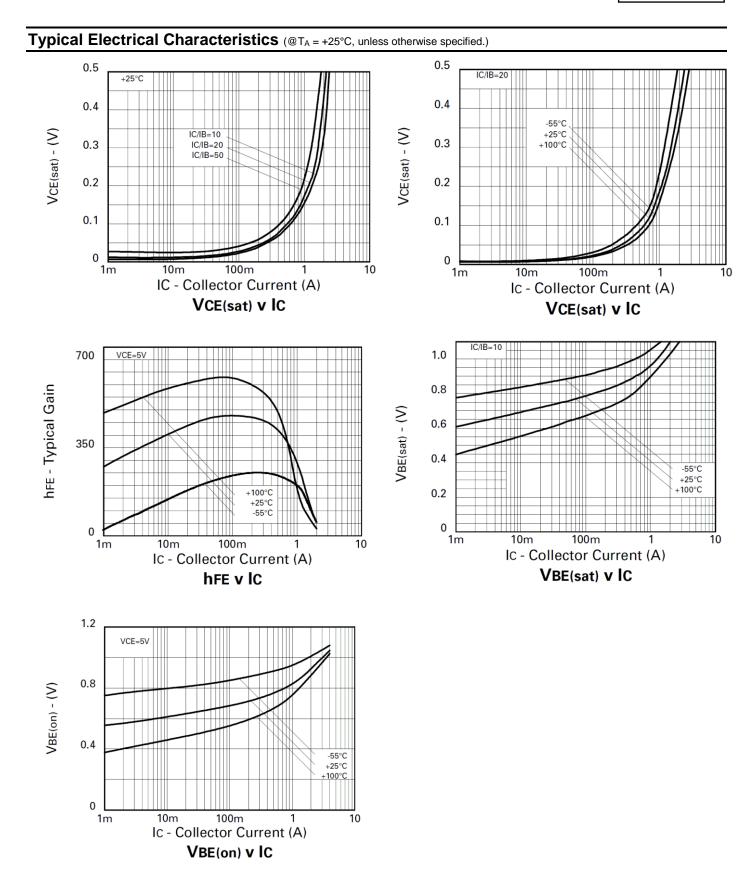


Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS	-					
Collector-Base Breakdown Voltage	BV _{CBO}	100	210	-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	50	70	-	V	I _C = 5mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.5	-	V	I _E = 100μA
Collector Cut-Off Current	I _{CBO}	-	-	10	nA	V _{CB} = 80V
Emitter Cut-Off Current	I _{EBO}	-	-	10	nA	$V_{EB} = 6V$
Collector Emitter Cut-Off Current	ICES	-	-	10	nA	$V_{CES} = 50V$
ON CHARACTERISTICS (Note 9)						•
Static Forward Current Transfer Ratio	hFE	200 300 200 100 30	400 450 400 230 50		-	$\begin{split} & I_{C} = 10 \text{mA}, \ V_{CE} = 5 \text{V} \\ & I_{C} = 200 \text{mA}, \ V_{CE} = 5 \text{V} \\ & I_{C} = 500 \text{mA}, \ V_{CE} = 5 \text{V} \\ & I_{C} = 1\text{A}, \ V_{CE} = 5 \text{V} \\ & I_{C} = 2\text{A}, \ V_{CE} = 5 \text{V} \end{split}$
Collector-Emitter Saturation Voltage	V _{CE(sat)}		24 60 100 195	45 100 180 330	mV	$\begin{split} I_{C} &= 100\text{mA}, \ I_{B} = 10\text{mA} \\ I_{C} &= 250\text{mA}, \ I_{B} = 10\text{mA} \\ I_{C} &= 500\text{mA}, \ I_{B} = 25\text{mA} \\ I_{C} &= 1.25, \ I_{B} = 125\text{mA} \end{split}$
Base-Emitter Saturation Voltage	V _{BE(sat)}	-	1020	1100	mV	$I_{\rm C} = 1.25$ A, $I_{\rm B} = 125$ mA
Base-Emitter Turn-On Voltage	V _{BE(on)}	-	895	1000	mV	$I_C = 1.25A, V_{CE} = 2V$
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f _T	-	180	-	MHz	$I_{C} = 50 \text{mA}, V_{CE} = 10 \text{V}, $ f = 100MHz
Collector Output Capacitance	C _{obo}	-	6	8	pF	$V_{CB} = 10V, f = 1MHz$
Turn-On Time	t _(on)	-	182	-	ns	$V_{CC} = 10V, I_C = 1A,$
Turn-Off Time	t _(off)	-	379	-	ns	$I_{B1} = -I_{B2} = 10 \text{mA}$

9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%. Note:





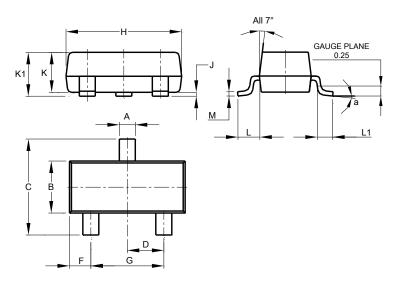






Package Outline Dimensions

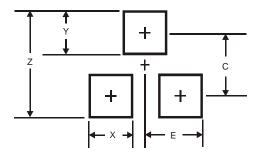
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
Κ	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
Μ	0.085	0.150	0.110		
а	8°				
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35





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